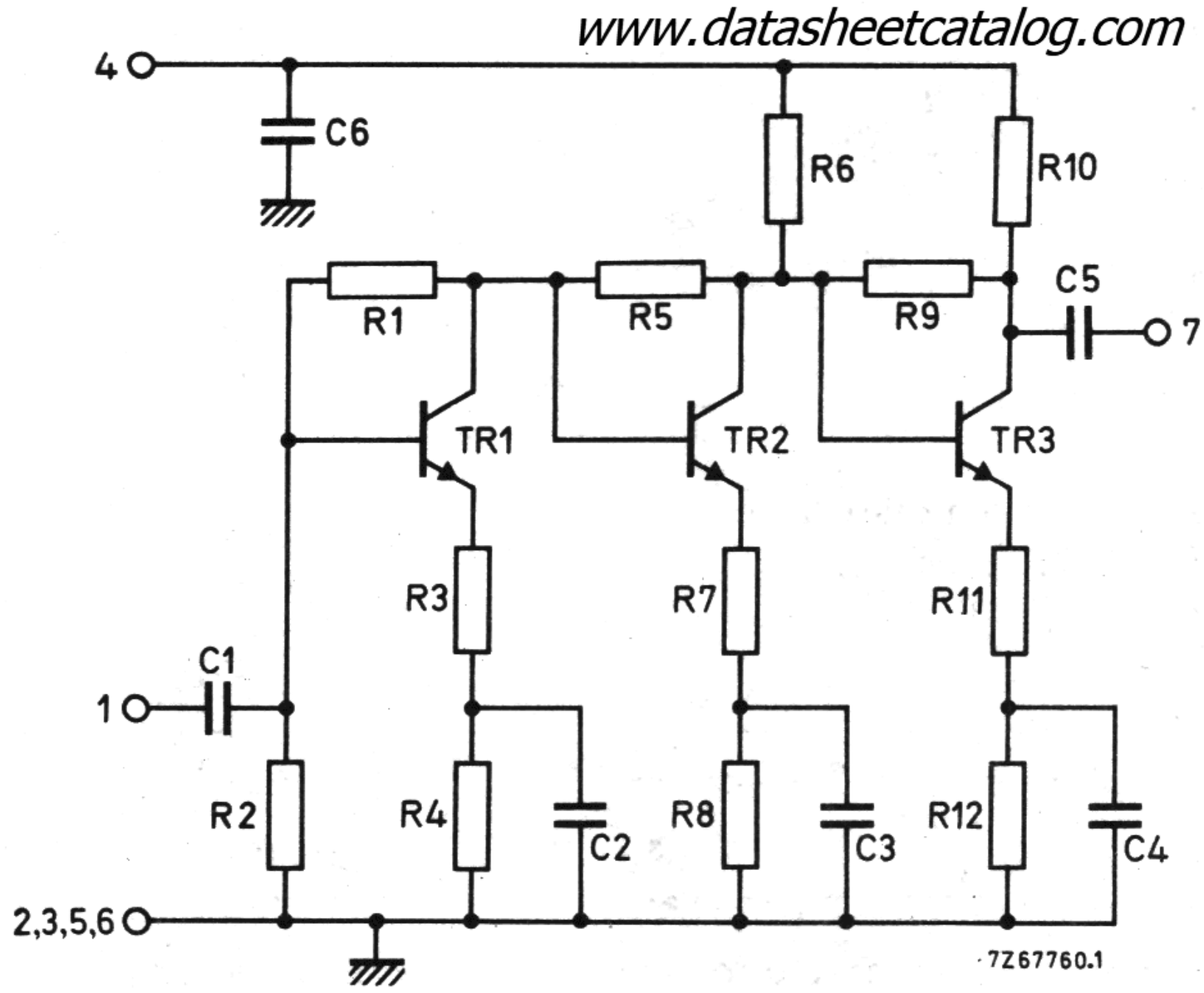
HYBRID VHF/UHF WIDE-BAND AMPLIFIER

Three-stage wide-band amplifier in the hybrid technique, designed for use in mast-head booster-amplifiers, as pre-amplifier in MATV systems, and as general-purpose amplifier for v.h.f. and u.h.f. applications.

QUICK REFERENCE DATA				
Frequency range	f		40 to 860	MHz
Source and load (characteristic) impedance	$R_s = R_\ell = Z_o$	=	75	Ω
Transducer gain	$G_{tr} = \|s_f\|^2$	typ.	27	dB
Flatness of frequency response	$\pm\Delta \|s_f\|^2$	typ.	1,6	dB
Output voltage at −60 dB intermodulation distortion (DIN45004, 3-tone)	$V_{o(rms)}$	>	98	dBμV
Noise figure	F	typ.	5,5	dB
D.C. supply voltage	V_B	=	24	V ±10%
Operating ambient temperature	T_{amb}	−20 to +70		°C

ENCAPSULATION 7-pin, in-line, resin-coated body, see MECHANICAL DATA

CIRCUIT DIAGRAM



RATINGS Limiting values in accordance with the Absolute Maximum System (IEC 134)

Operating ambient temperature	T_{amb}		−20 to +70	°C
Storage temperature	T_{stg}		−40 to +125	°C
D.C. supply voltage	V_B	max.	28	V
Peak voltages on pins 1 and 7	V_{1M}, V_{7M}	max.	28	V
	$-V_{1M}$, $-V_{7M}$	max.	10	V
Peak incident powers on pins 1 and 7	P_{I1M}, P_{I7M}	max.	100	mW

CHARACTERISTICS

Measuring conditions

V.H.F.-U.H.F. test socket	catalogue no. 3504 110 01840 *			
Ambient temperature	T_{amb}	=	25	°C
D.C. supply voltage	V_B	=	24	V
Source impedance and load impedance	R_s, R_ℓ	=	75	Ω
Characteristic impedance of h.f. connections	Z_o	=	75	Ω
Frequency range	f	=	40 to 860	MHz

Performance

Supply current	I_B	typ.	35	mA
Transducer gain	$G_{tr} = \lvert s_f \rvert^2$		23 to 31	dB
		typ.	27	dB
Flatness of frequency response	$\pm\Delta \lvert s_f \rvert^2$	typ.	1,6	dB
Individual maximum v.s.w.r.				
input	$VSWR_{(i)}$	typ.	1,9	**
output	$VSWR_{(o)}$	typ.	3,2	**
Back attenuation				
f = 100 MHz	$\lvert s_r \rvert^2$	typ.	46	dB
f = 860 MHz	$\lvert s_r \rvert^2$	typ.	40	dB
Output voltage				
at −60 dB intermodulation distortion (DIN45004, par. 6.3: 3-tone)	$V_{o(rms)}$	>	98	dBμV
		typ.	101	dBμV
Noise figure	F	typ.	5,5	dB

s-parameters:	$s_f = s_{21}$	$s_i = s_{11}$
	$s_r = s_{12}$	$s_o = s_{22}$

* This socket can be made available for customer reference purposes.

** Highest value, for a sample, occurring in the frequency range.

OPERATING CONDITIONS

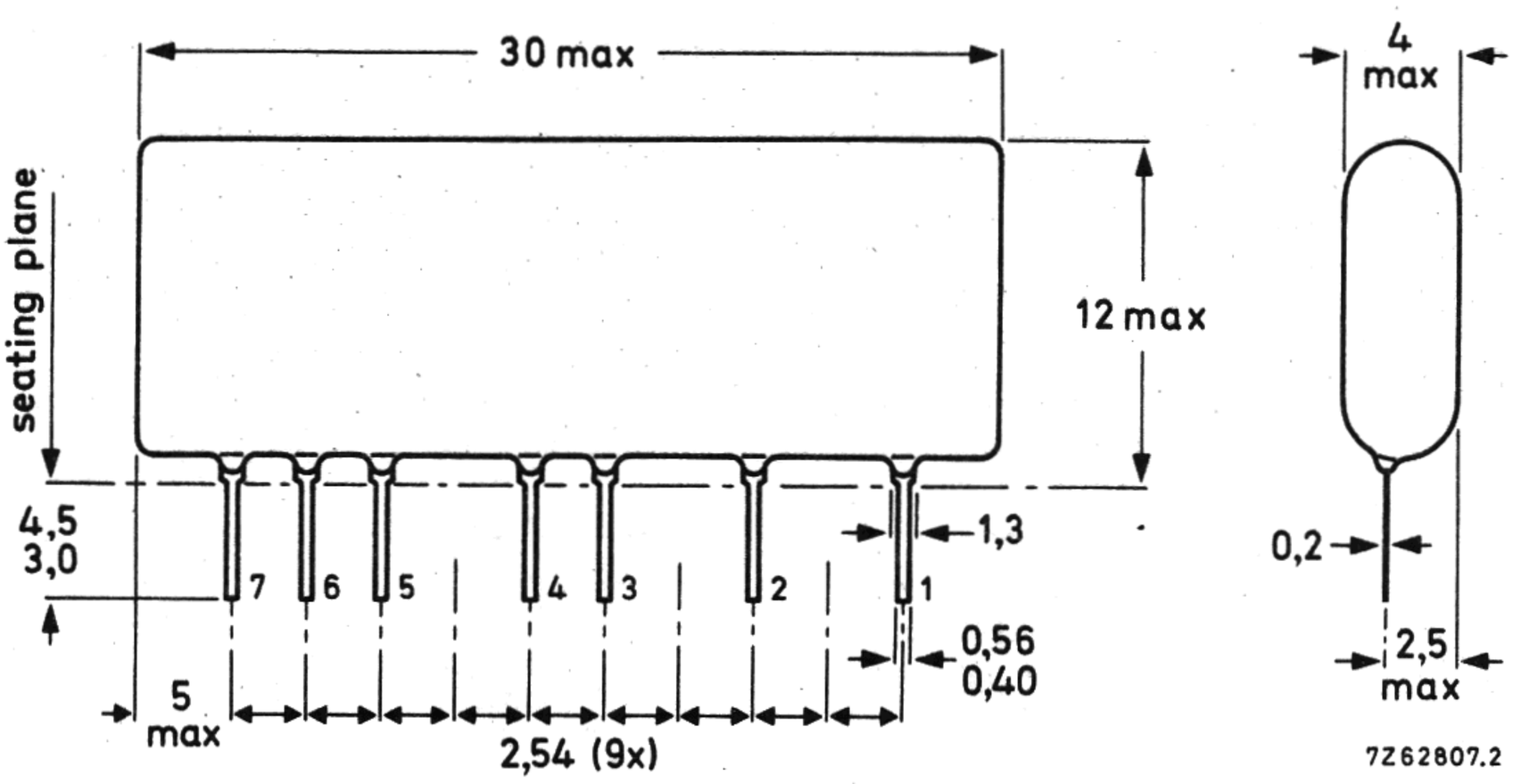
Ambient temperature range	T_{amb}		−20 to +70	°C
D.C. supply voltage	V_B	=	24	V ±10%
Frequency range	f		40 to 860	MHz
Source impedance and load impedance	R_s, R_ℓ	=	75	Ω

MECHANICAL DATA

Dimensions in mm

Encapsulation

The device is resin coated.



Terminal connections

1	= Input
2, 3, 5, 6	= Common
4	= Supply (+)
7	= Output

Soldering recommendations

Hand soldering

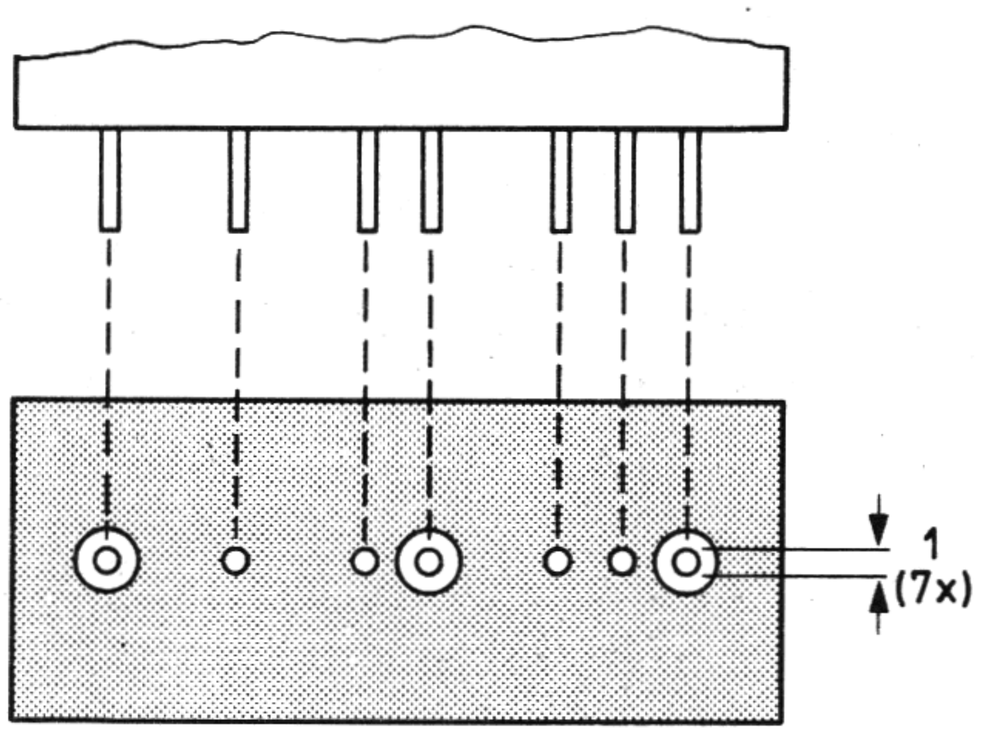
Maximum contact time for a soldering-iron temperature of 260 °C; up to seating plane: 5 s

Dip or wave soldering

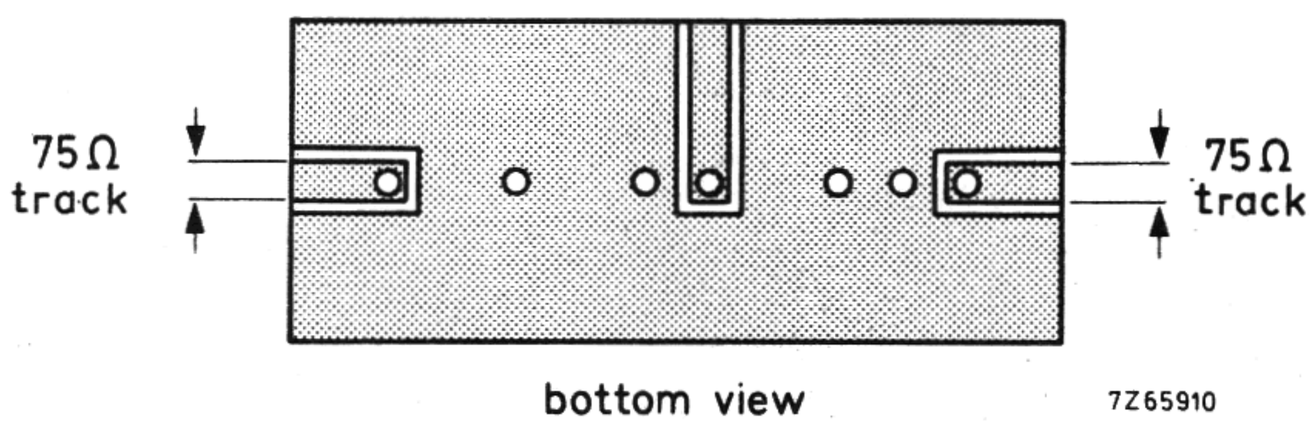
260 °C is the maximum permissible temperature of the solder; it must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.
The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

Mounting recommendations

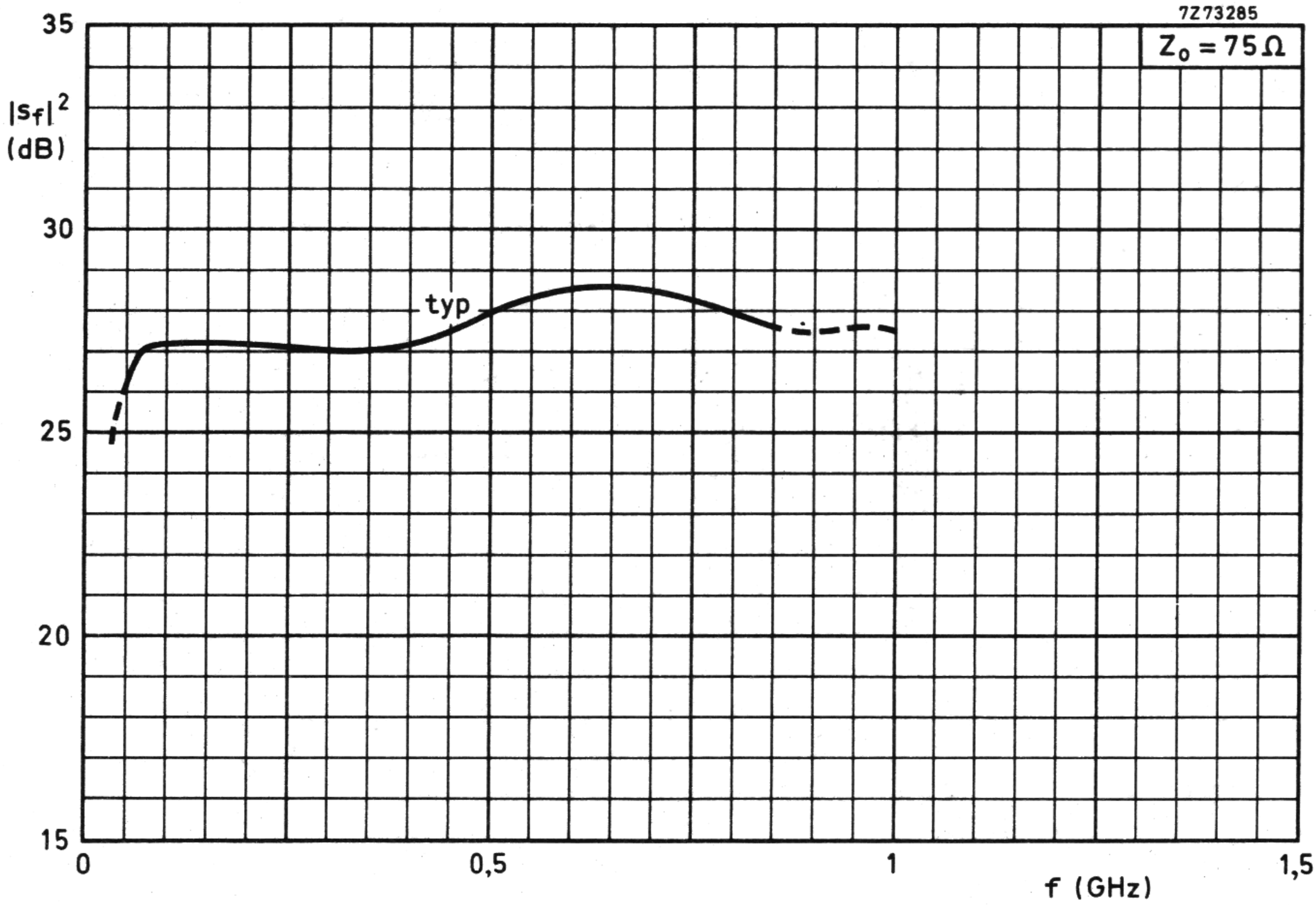
The module should preferably be mounted on double-sided printed-circuit board, see the example shown below.
Input and output should be connected to 75 Ω tracks.
The connections to the "common" pins should be as close to the seating plane as possible.

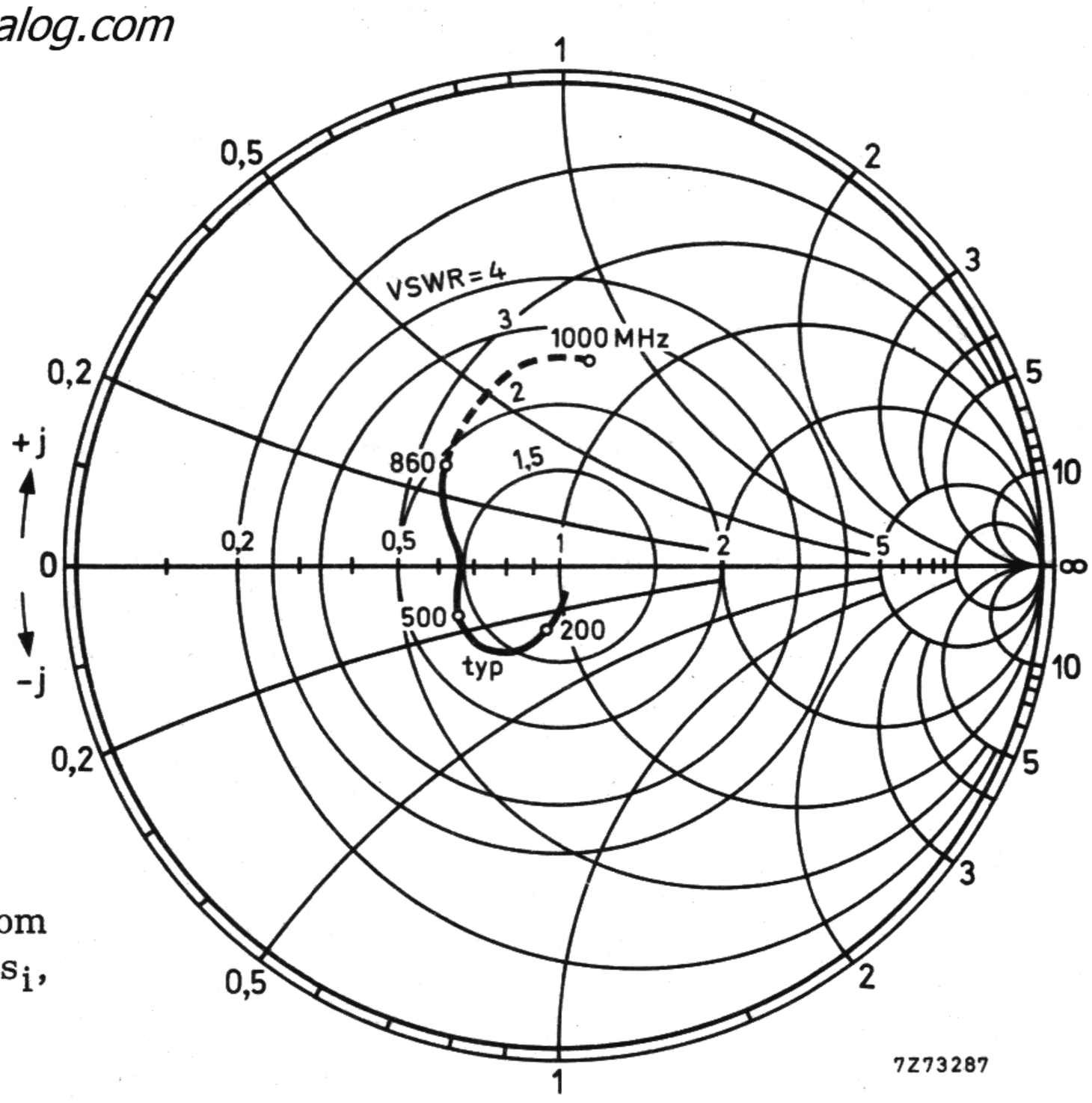


top view

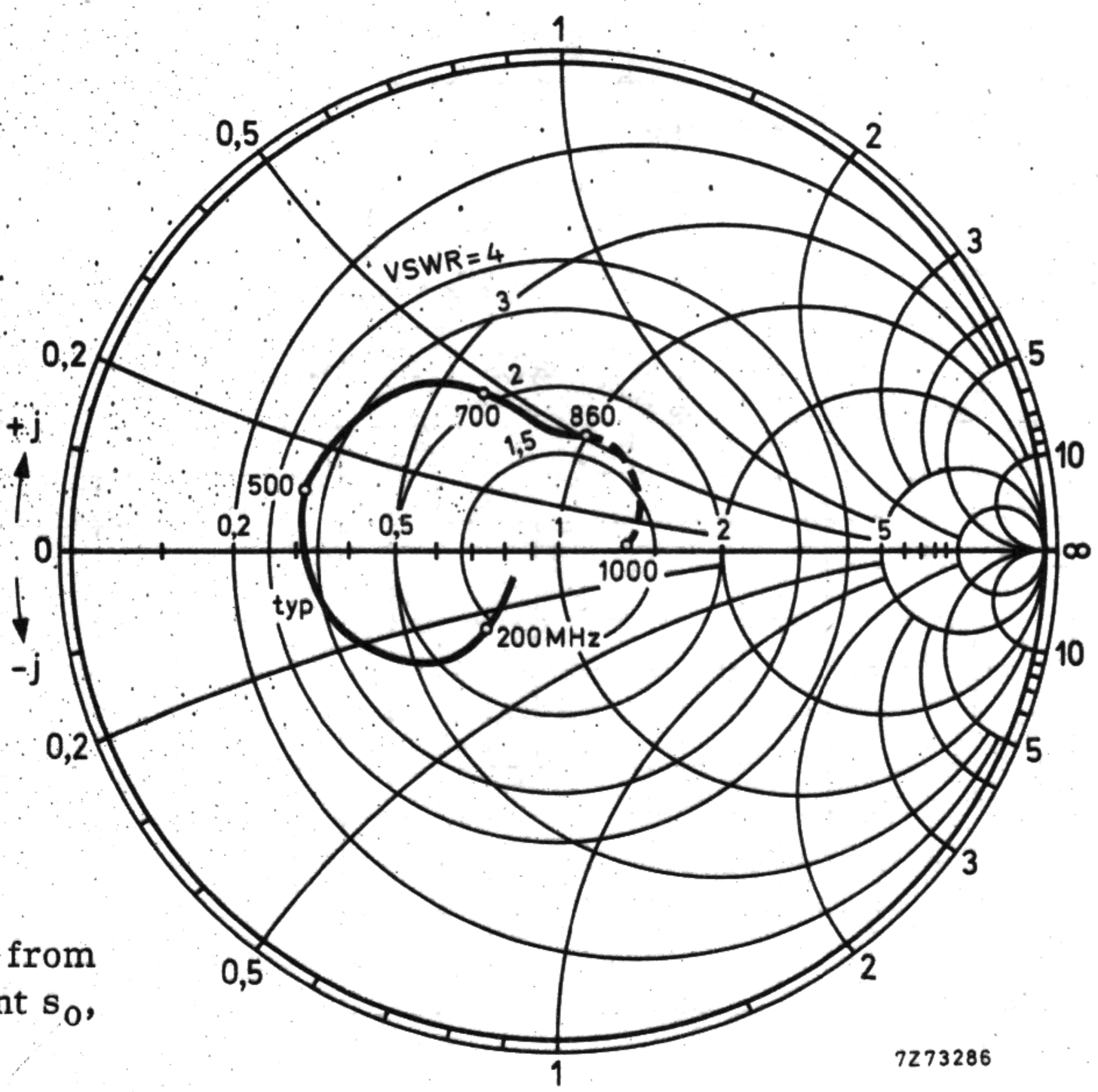


bottom view 7Z65910





Input impedance derived from input reflection coefficient s_i, co-ordinates in ohm x 75.



Output impedance derived from output reflection coefficient s_o, co-ordinates in ohm x 75.